NSN 5961-01-082-1981

Transistor - Page 1 of 1

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View Online at https://aerobasegroup.com/nsn/5961-01-082-1981 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.230 inches **Internal Configuration:** Field effect-dual gate Joint Electronic Device Engineering Council/jedec/case Outline Designation: T0-71 **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 50.0 breakdown voltage, gate-to-source, with all other terminals short-circuited to source **Current Rating Per Characteristic:** 10.00 milliamperes zero-gate-voltage source current megawatts **Power Rating Per Characteristic:** 500.0 milliwatts small-signal input power, common-collector absolute **Special Features:** boltage ratting **Terminal Type And Quantity:** 8 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: